Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!

Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832
Email & Skype: info@chipsmall.com Web: www.chipsmall.com
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

High Voltage LED Series
Chip on Board

LC019D– Gen.2

High efficacy COB LED package
well-suited for use in spotlight applications

Features & Benefits

- Chip on Board (COB) solution makes it easy to design in
- Simple assembly reduces manufacturing cost
- Low thermal resistance
- InGaN/GaN MQW LED with long time reliability

Applications

- Spotlight / Downlight
- LED Retrofit Bulbs
- Outdoor Illumination

Table of Contents

1. Characteristics

a) Absolute Maximum Rating

Item	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	T_a	-40 ~ +105	ºC	-
Storage Temperature	T_{stg}	-40 ~ +120	ºC	-
LED Junction Temperature	T_J	150	ºC	-
Case Temperature	Tc	115	ºC	
Forward Current	I_F	1380	mA	-
Power Dissipation	P_D	51.8	W	-
ESD (HBM)	-	±2	kV	-
ESD (MM)	-	±0.5	kV	-

b) Electro-optical Characteristics (I_F = 540 mA, T_J = 85 ºC)

Item	Unit	Rank	Min.	Typ.	Max.
Forward Voltage (V_F)	V	YZ	31.8	34.6	37.5
Color Rendering Index (R_a)	-	3	70	-	-
		5	80	-	-
		7	90		
Thermal Resistance (junction to case point)	ºC/W		-	0.6	-
Beam Angle	º		-	115	-
Nominal Power	W			18.7	

Notes:

1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature (T_J = T_C = T_a = 85 °C)
2) Samsungmaintains measurement tolerance of: forward voltage = ±5 %, CRI = ±1
3) Refer to the derating curve, ‘3. Typical Characteristics Graph’designed within the range.

c) Luminous Flux Characteristics (I_F = 540 mA)

CRI (R_a) Min.	Nominal CCT (K)	Flux Rank	Flux@ T_c = 85 °C (lm)		
			Min.	Typ.	Max.
70	3000	D2	2952	3107	-
	4000	D2	3046	3207	-
	5000	D2	3093	3256	-
80	2700	D2	2592	2728	-
	3000	D2	2733	2877	-
	3500	D2	2817	2965	-
	4000	D2	2875	3026	-
	5000	D2	2906	3059	-
	5700	D2	2906	3059	-
	6500	D2	2875	3026	-
90	2700	D2	2219	2336	-
	3000	D2	2327	2449	-
	3500	D2	2412	2539	-
	4000	D2	2465	2594	-
	5000	D2	2467	2596	-

Notes:

1) The COB is tested in pulsed operating condition at rated test current (10 ms pulse width) and rated temperature (T_J = T_C = 85 °C).
2) Samsungmaintains measurement tolerance of: Luminous flux = ±7 %, CRI = ±1

2. Product Code Information

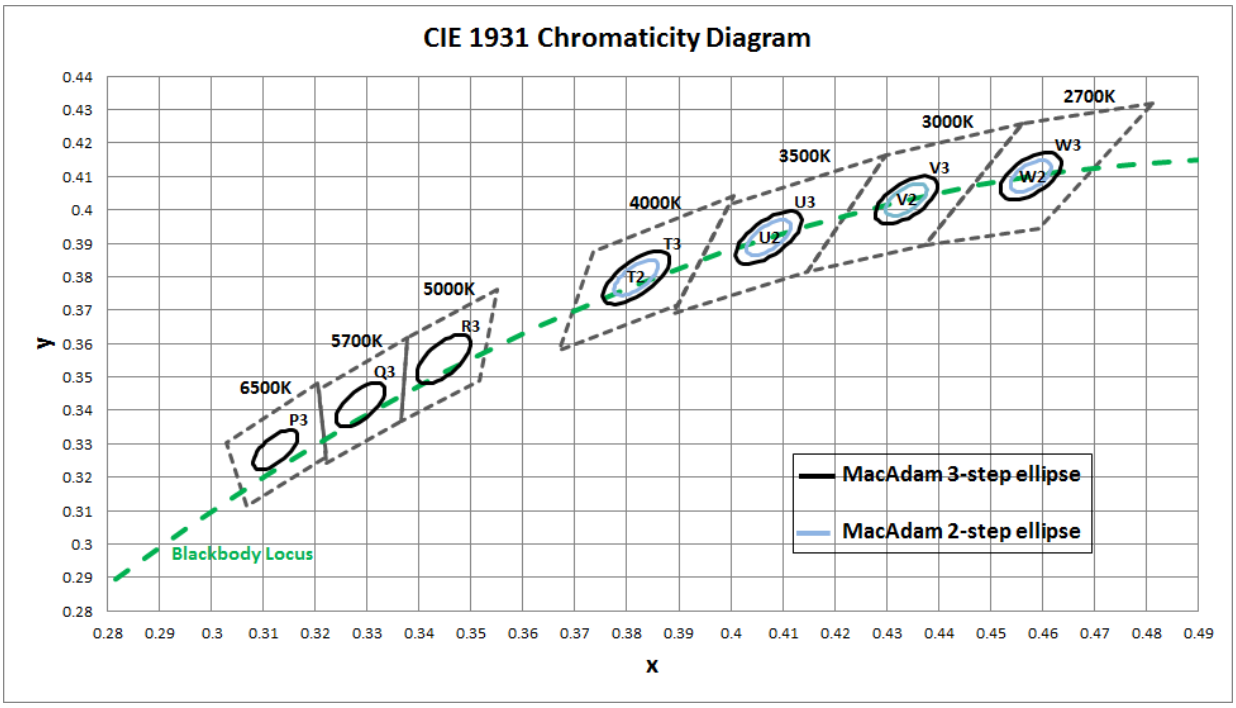
1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	P	H	W	H	A	H	D	N	F	2	5	Y	Z	W	3	D	2

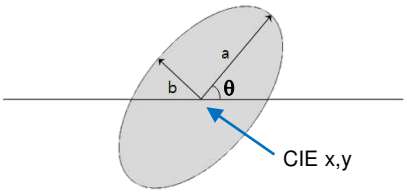
Digit	PKG Information	Code	Specification
1 2 3	Samsung Package High Power	SPH	
4 5	Color	WH	White
6	Product Version	A	
7 8	Form Factor	HD	COB
9	Lens Type	N	No lens
10	Wattage or Model	F	LC019D
11	Internal Code	2	
12	CRI & Sorting Temperature	3	Min. 70 (85℃)
		5	Min. 80 (85℃)
		7	Min. 90 (85℃)
13 14	Forward Voltage (V)	YZ	31.8~37.5
15	CCT (K)	W	2700K
		V	3000K
		U	3500K
		T	4000K
		R	5000K
		Q	5700K
		P	6500K
16	MacAdam Step	2	MacAdam 2-step
		3	MacAdam 3-step
17 18	Luminous Flux (Lm)	D2	COB D-series Gen.2 level

a) Binning Structure (I_F = 540 mA, T_J = 85 ºC)

CRI(R_a) Min.	Nominal CCT(K)	Product Code	V_F Rank	Color Rank	Flux Rank	Flux Range (Φ_v, lm)
70	3000	SPHWHAHDNF23YZV3D2	YZ	V3	D2	2952 ~
	4000	SPHWHAHDNF23YZT3D2	YZ	T3	D2	3046 ~
	5000	SPHWHAHDNF23YZR3D2	YZ	R3	D2	3093 ~
80	2700	SPHWHAHDNF25YZW2D2	YZ	W2	D2	2592 ~
		SPHWHAHDNF25YZW3D2		W3		
	3000	SPHWHAHDNF25YZV2D2	YZ	V2	D2	2733 ~
		SPHWHAHDNF25YZV3D2		V3		
	3500	SPHWHAHDNF25YZU2D2	YZ	U2	D2	2817 ~
		SPHWHAHDNF25YZU3D2		U3		
	4000	SPHWHAHDNF25YZT2D2	YZ	T2	D2	2875 ~
		SPHWHAHDNF25YZT3D2		T3		
	5000	SPHWHAHDNF25YZR3D2	YZ	R3	D2	2906 ~
	5700	SPHWHAHDNF25YZQ3D2	YZ	Q3	D2	2906 ~
	6500	SPHWHAHDNF25YZP3D2	YZ	P3	D2	2875 ~
90	2700	SPHWHAHDNF27YZW2D2	YZ	W2	D2	2219 ~
		SPHWHAHDNF27YZW3D2		W3		
	3000	SPHWHAHDNF27YZV2D2	YZ	V2	D2	2327 ~
		SPHWHAHDNF27YZV3D2		V3		
	3500	SPHWHAHDNF27YZU2D2	YZ	U2	D2	2412 ~
		SPHWHAHDNF27YZU3D2		U3		
	4000	SPHWHAHDNF27YZT2D2	YZ	T2	D2	2465 ~
		SPHWHAHDNF27YZT3D2		T3		
	5000	SPHWHAHDNF27YZR3D2	YZ	R3	D2	2467 ~

b) Chromaticity Region & Coordinates (I_F = 540 mA, T_J = 85 ºC)





MacAdam Ellipse (W2, W3)					
Step	CIE x	CIE y	θ	a	b
2-step	0.4578	0.4101	53.70	0.0054	0.0028
3-step	0.4578	0.4101	53.70	0.0081	0.0042

MacAdam Ellipse (V2, V3)					
Step	CIE x	CIE y	θ	a	b
2-step	0.4338	0.403	53.22	0.0056	0.0027
3-step	0.4338	0.4030	53.22	0.0083	0.0041

MacAdam Ellipse (U2, U3)					
Step	CIE x	CIE y	θ	a	b
2-step	0.4073	0.3917	54.00	0.0062	0.0028
3-step	0.4073	0.3917	54.00	0.0093	0.0041

MacAdam Ellipse (T2, T3)					
Step	CIE x	CIE y	θ	a	b
2-step	0.3818	0.3797	53.72	0.0063	0.0027
3-step	0.3818	0.3797	53.72	0.0094	0.0040

MacAdam Ellipse (R3)					
Step	CIE x	CIE y	θ	a	b
3-step	0.3447	0.3553	59.62	0.0082	0.0035

MacAdam Ellipse (Q3)					
Step	CIE x	CIE y	θ	a	b
3-step	0.3287	0.3417	59.0950	0.0075	0.0032

MacAdam Ellipse (P3)					
Step	CIE x	CIE y	θ	a	b
3-step	0.3123	0.3282	58.5700	0.0067	0.0029

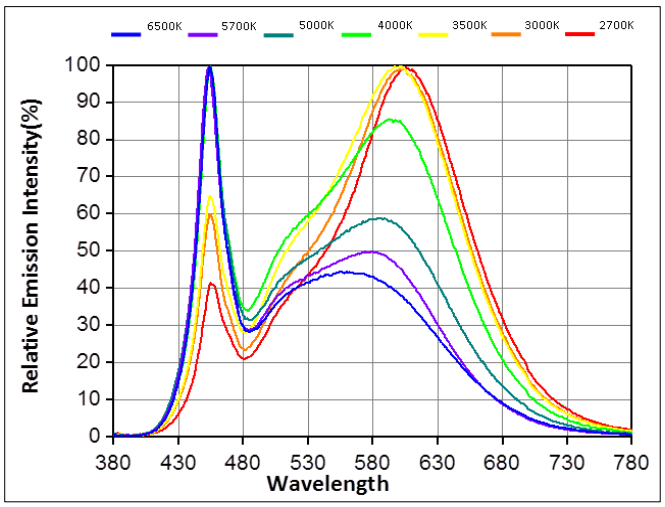
Note:

Samsung maintains measurement tolerance of: Cx, Cy = ±0.005

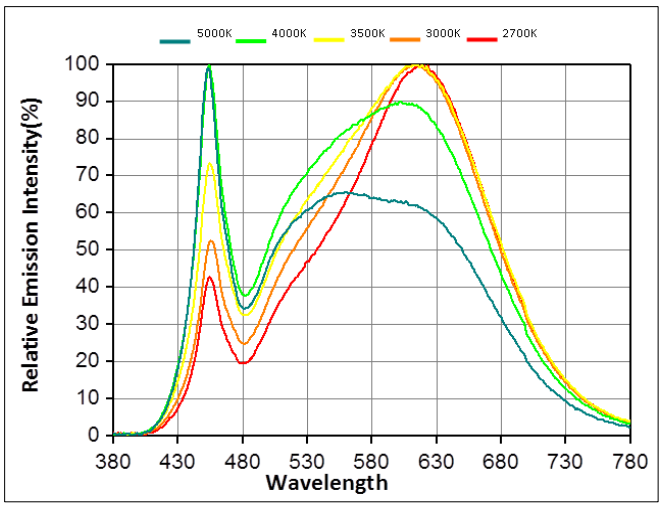
3. Typical Characteristics Graphs

a) Spectrum Distribution (I_F = 540mA, T_J = 85 ºC)

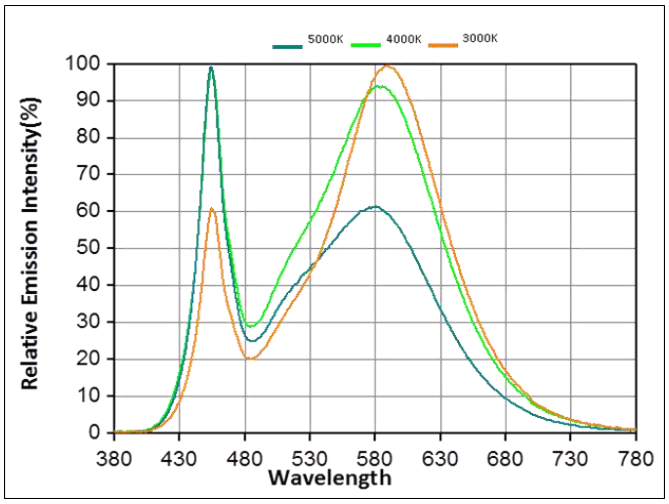
CRI Ra 80+



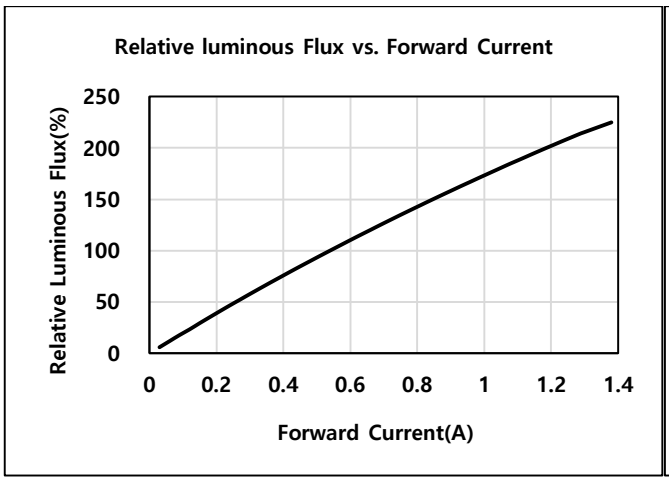
CRI Ra 90+

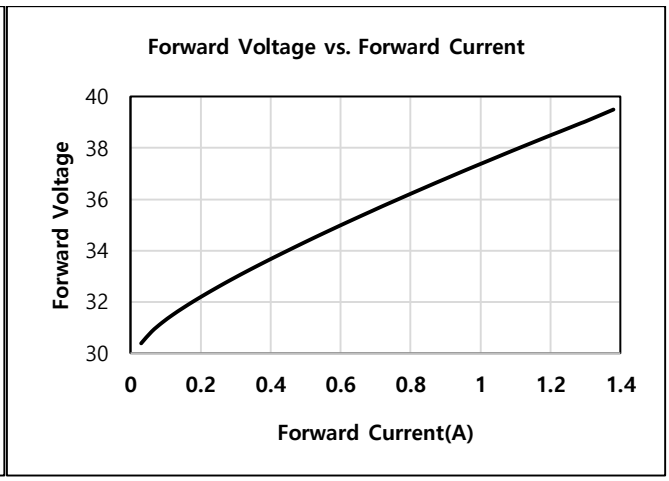


CRI Ra 70+

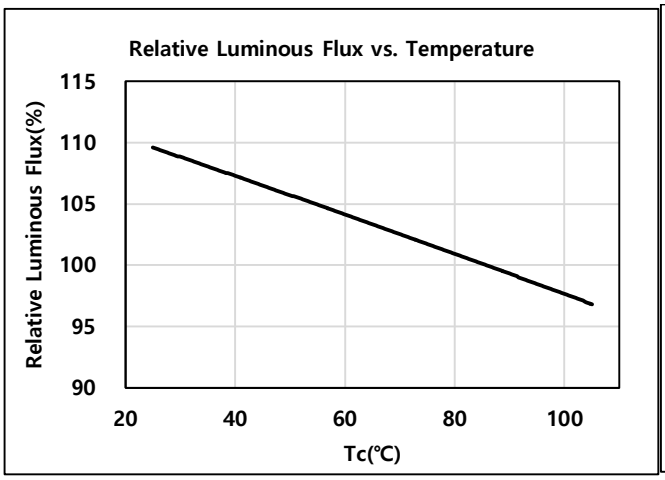


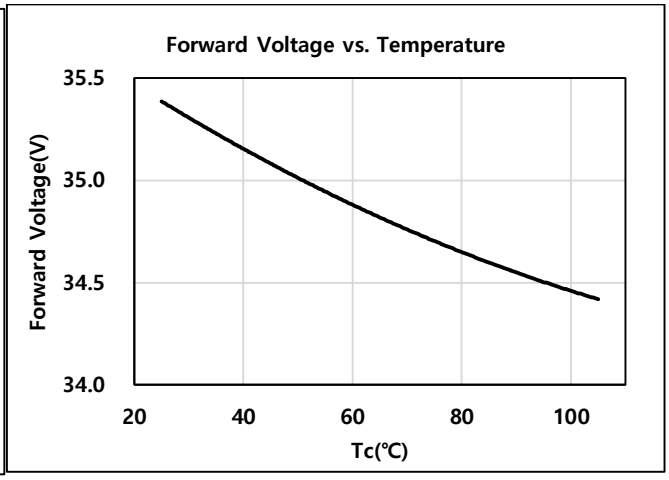
b)Forward Current Characteristics (T_J = 85 ºC)



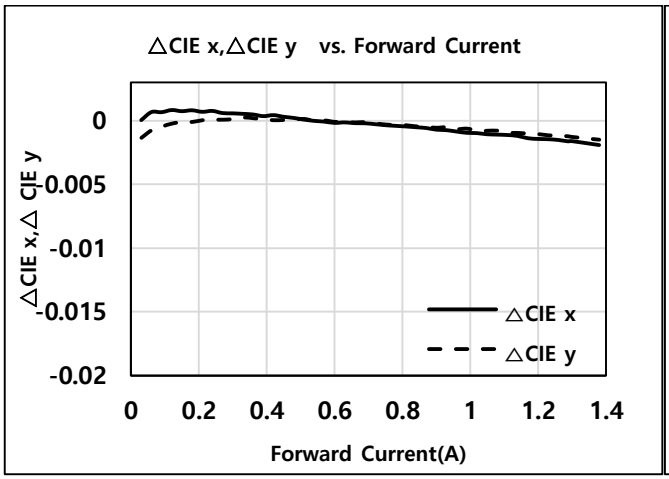


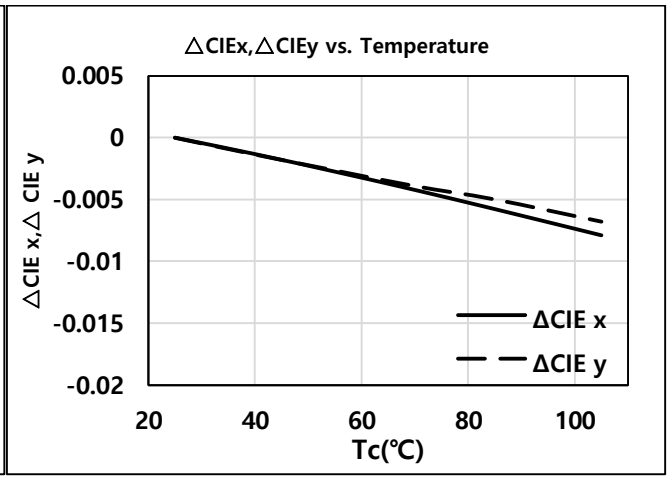
c) Temperature Characteristics(I_F = 540mA)



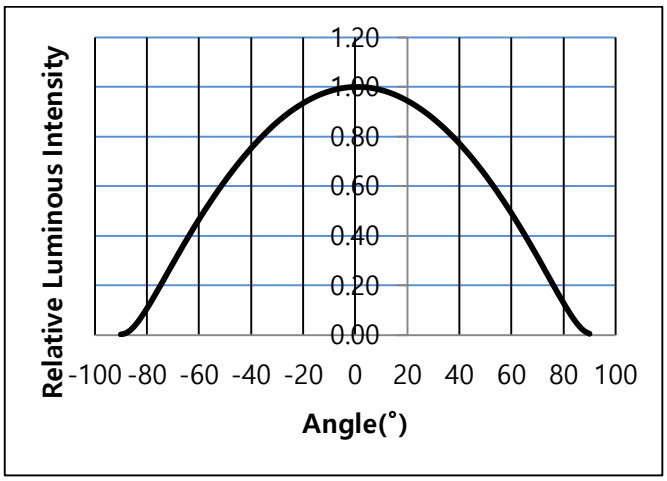


d) Color Shift Characteristics (T_J = 85 ºC,I_F =540mA, CRI = 80+)

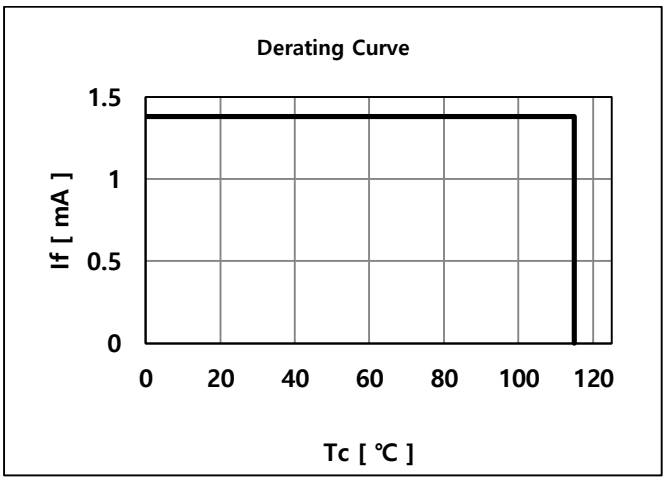




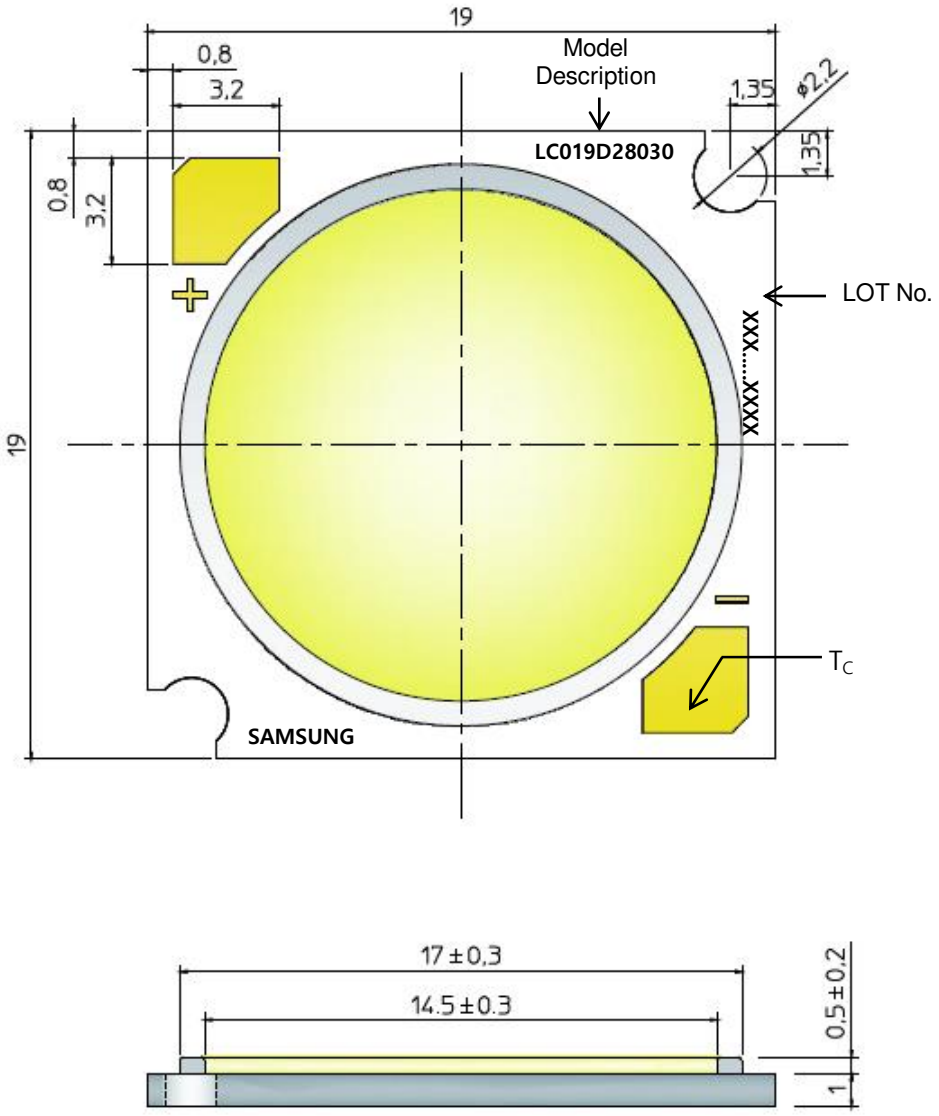
e) Beam Angle Characteristics (I_F = 540 mA, T_J = 85 ºC)



f) Derating Characteristics



4. Outline Drawing & Dimension



1. Unit: mm
2. Tolerance: ± 0.3 mm

Item	Dimension	Tolerance	Unit
Length	19.0	±0.30	mm
Width	19.0	±0.30	mm
Height	1.50	±0.20	mm
Light Emitting Surface (LES) Diameter	14.5	±0.30	mm

Note: Denoted product information above is only an example
(LC019D28030 : LC019D, Gen2, CRI80+, 3000K)

5. Reliability Test Items & Conditions

a) Test Items

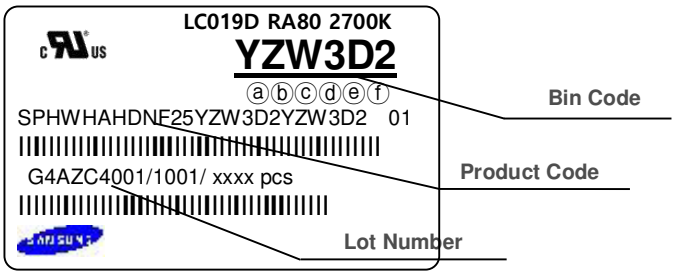
Test Item	Test Condition	Test Hour / Cycle
High Temperature Humidity Life Test	60 ºC, 90 % RH,, DC Derating, I_F	1000 h
High Temperature Life Test	85 ºC, DC Derating, I_F	1000 h
Low Temperature Life Test	-40 ºC, DC, Derating I_F	1000 h
High Temperature Storage	120 ºC	1000 h
Low Temperature Storage	-40 ºC	1000 h
Temperature Humidity Storage	60 ºC, 90% RH	1000h
TemperatureCycle On/Off Test	-40 ºC/ 85 ºC each 20 min, 30 min transfer power on/off each 5 min, DC Derating, I_F = max	100 cycles
ESD (HBM)	R_1: 10 MΩ R_2: 1.5 kΩ C: 100 pF	5 times
ESD (MM)	R_1: 10 MΩ R_2: 0 kΩ C: 200 pF	5 times
Vibration Test	20~ 80 Hz (displacement: 0.06 inch, max. 20 g) 80 ~ 2 kHz (max. 20 g) min. frequency ↔max. frequency 4 min transfer	4 times
Mechanical Shock Test	1500g, 0.5 ms each of the 6 surfaces (3 axis x 2 sides)	5 times
Sulfur Resistance	25 °C, 75%, H2S 15 ppm	504h

b) Criteria for Judging the Damage

Item	Symbol	Test Condition (T_c = 25 ºC)	Limit	
			Min.	Max.
Forward Voltage	V_F	I_F = 540 mA	L.S.L. * 0.9	U.S.L. * 1.1
Luminous Flux	Φ_v	I_F = 540 mA	L.S.L * 0.7	U.S.L * 1.3

6. Label Structure

a) Label Structure



Note: Denoted bincode and product code above is only an example (see description on page 5)

Bin Code:

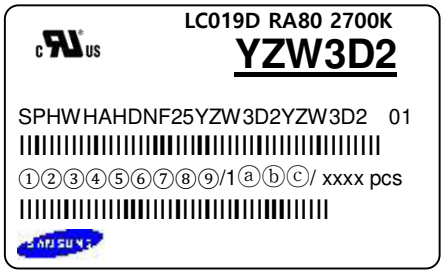
ⓐⓑ: Forward Voltagebin (refer to page11)

ⓒⓓ: Chromaticitybin (refer to page 9-10)

ⓔⓕ: Luminous Fluxbin (refer to page 6)

b) Lot Number

The lot number is composed of the following characters:



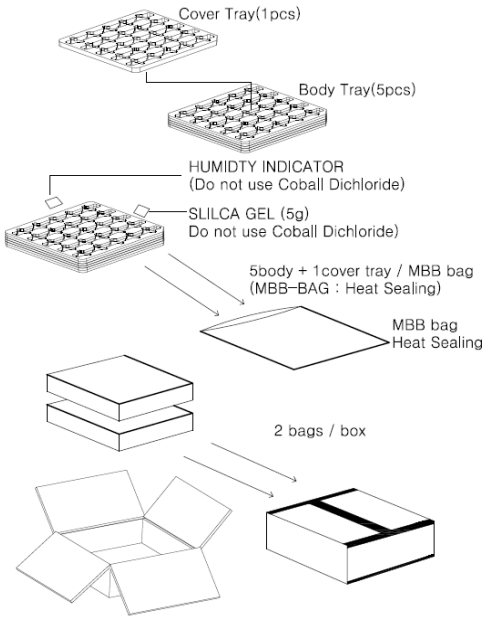
① ③④⑤⑥⑦⑧⑨ / 1ⓐⓑⓒ / xxxx pcs

①	:	Production site (S: Giheung, Korea, G: Tianjin, China)
②	:	4(LED)
③	:	Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)
④	:	Year (Z: 2015, A: 2016, B: 2017…)
⑤	:	Month (1~9, A, B, C)
⑥⑦⑧⑨	:	Day (1~9, A, B~V)
ⓐⓑⓒ	:	Product serial number (001 ~ 999)

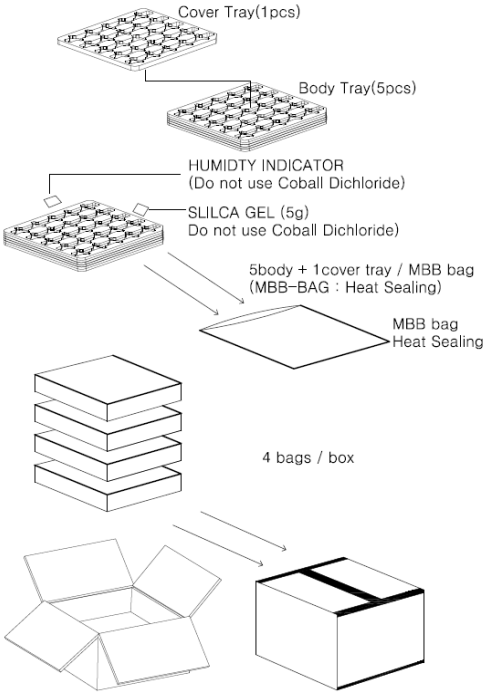
7. Packing Structure

Packing material	Max. quantity in pcs of COB	Dimension(mm)			
		Length	Width	Height	Tolerance
Tray	25	200	200	8	1
Anti-Static Bag	125 (5 trays)	320	270	-	+/- 0.5
Outer Box (Small)	250 (2 bags)	225	225	65	5
Outer Box (Middle)	500 (4 bags)	225	225	130	5

a) Packing Structure

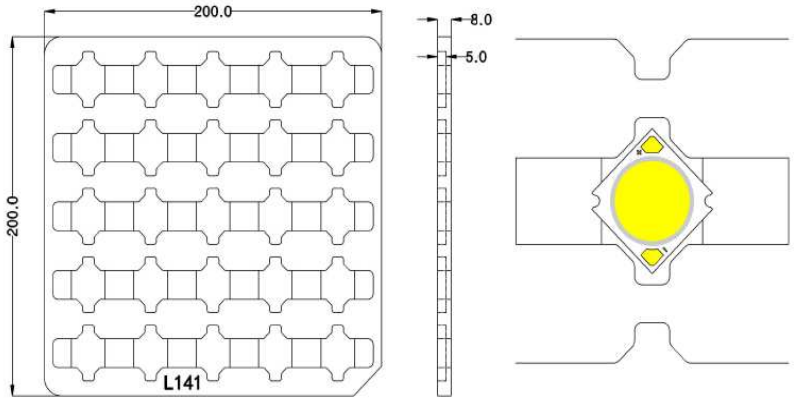


※ Small Box



※ Middle Box

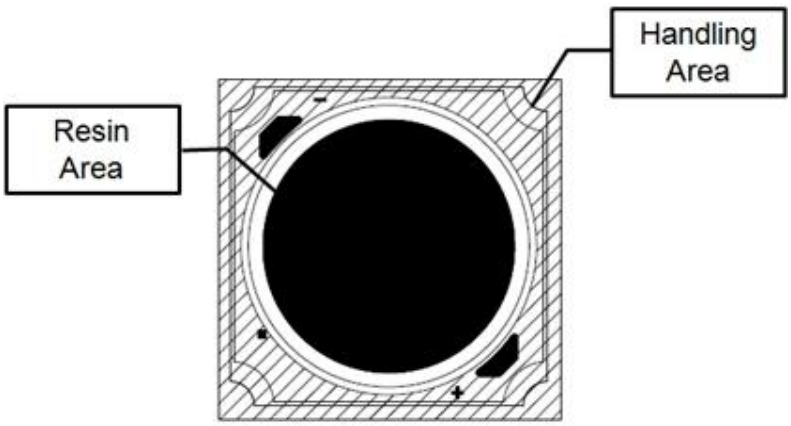
b) Tray



8. Precautions in Handling & Use

1) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
2) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 ºC, 0~90 % RH).
3) After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
   a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 ºC / 60 % RH, or
   b. Stored at <10 % RH
4) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
5) Devices require baking before mounting, if humidity card reading is >60 % at 23 ± 5 ºC.
6) Devices must be baked for 1 hour at 60 ± 5 ºC, if baking is required.
7) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
8) The thermal management is one of the most critical factors for the LED lighting system. Especially the LED junction temperature should not exceed the absolute maximum rating while operation of LED lighting system.

   For more information, please refer to Application Note ‘Mechanical & Thermal Guide for COB’.
9) In case of driving LEDsaround the minimum current level (If_min), chips might exhibit different brightness due to the variation in I-V characteristics of each one. This is normal and does not adversely affect the performance of product.
10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
11) The resin area is very sensitive, please do not handle, press, touch, rub, clean, or pick by with tweezers on it. Instead, please pick at the handling area as indicated below.



Legal and additional information.

About Samsung Electronics Co., Ltd.

Samsung Electronics Co., Ltd. inspires the world and shapes the future with transformative ideas and technologies, redefining the worlds of TVs, smartphones, wearable devices, tablets, cameras, digital appliances, printers, medical equipment, network systems and semiconductors. We are also leading in the Internet of Things space through, among others, our Digital Health and Smart Home initiatives. We employ 307,000 people across 84 countries. To discover more, please visit our official website at www.samsung.com and our official blog at global.samsungtomorrow.com.

Samsung Electronics Co., Ltd.
95, Samsung 2-ro
Giheung-gu
Yongin-si, Gyeonggi-do, 446-711
KOREA

www.samsungled.com

SAMSUNG